



R1200 THRU R2000

HIGH VOLTAGE SILICON RECTIFIER

Reverse Voltage - 1200 to 2000 Volts Forward Current - 0.5 Ampere

FEATURES

- Low cost
- Low leakage
- Low forward voltage drop
- High current capability

MECHANICAL DATA

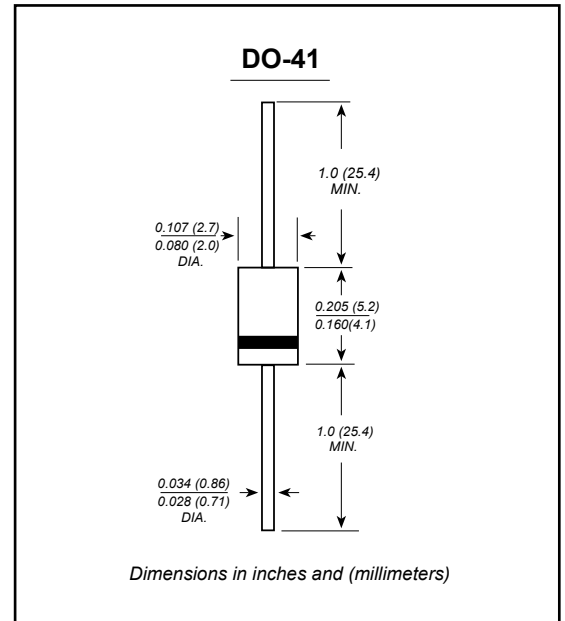
Case: JEDEC DO-41 molded plastic body

Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.012 ounce, 0.33 grams



Maximum Ratings and Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	R1200	R1500	R1800	R2000	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	1200	1500	1800	2000	V
RMS Reverse Voltage	$V_{R(RMS)}$	840	1050	1260	1400	V
Average Rectified Output Current (Note 1) @ $T_A= 50^{\circ}\text{C}$	I_O	500				mA
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30				A
Forward Voltage @ $I_F= 500\text{mA}$	V_{FM}	2.0			3.0	V
Peak Reverse Leakage Current at Rated DC Blocking Voltage	I_{RM}	5.0				μA
Typical Junction Capacitance (Note 2)	C_j	30				pF
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	70			117	K/W
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150				$^{\circ}\text{C}$

Notes: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.



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RATINGS AND CHARACTERISTIC CURVES

FIG.1 - FORWARD CURRENT DERATING CURVE

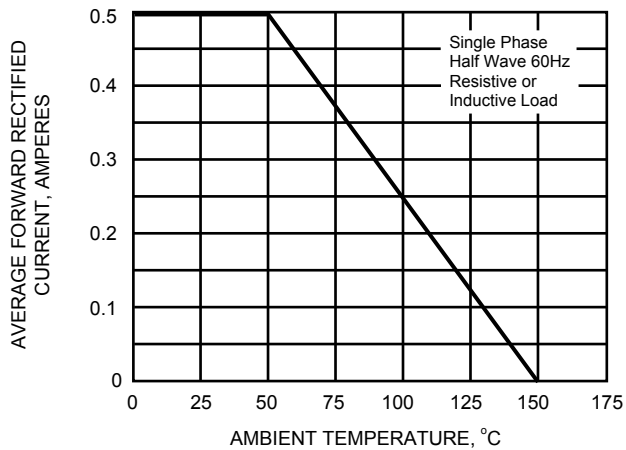


FIG.2 - MAXIMUM NON-REPETITIVE
PEAK FORWARD SURGE CURRENT

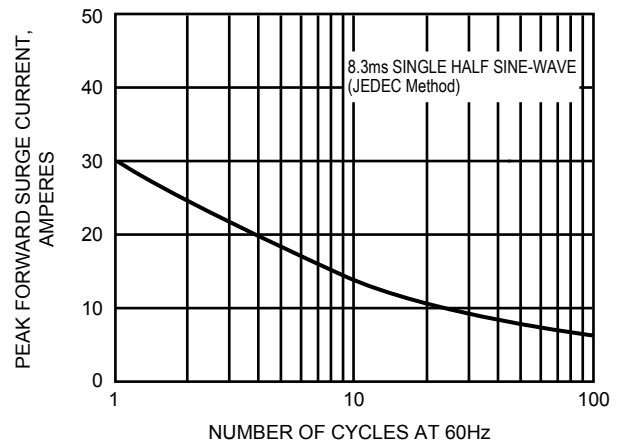


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

